



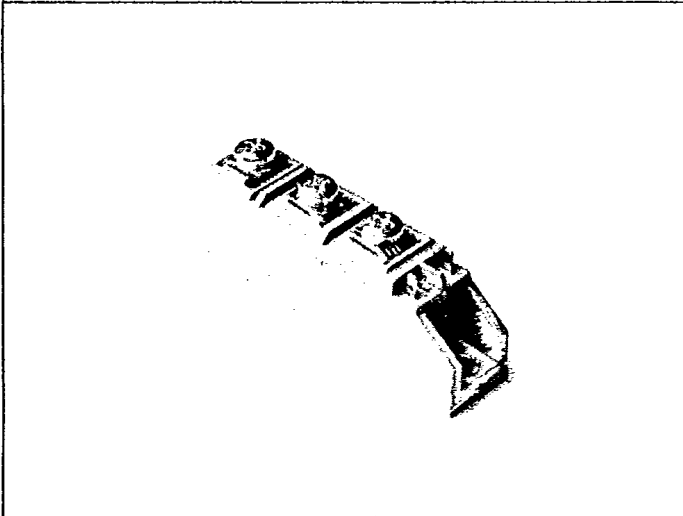
SILICON POWER CUBE

F-18 SERIES 25A-90A POWER SCR/DIODE MODULES

T-23-07
T-25-17

FEATURES

- Thirteen standard module configurations available
- Standard voltages of 200 volts to 1400 volts. Average device current output ratings of 25 amps to 90 amps
- Ultra-high surge current capabilities
- SPC's unitized power hybrid technology provides highly efficient thermal management for greatly extended cyclic life
- UL Component Recognition
- 2500VAC RMS terminal-to-base isolation
- All units are 100% tested at both 25° C and 125° C temperature levels — for assured quality

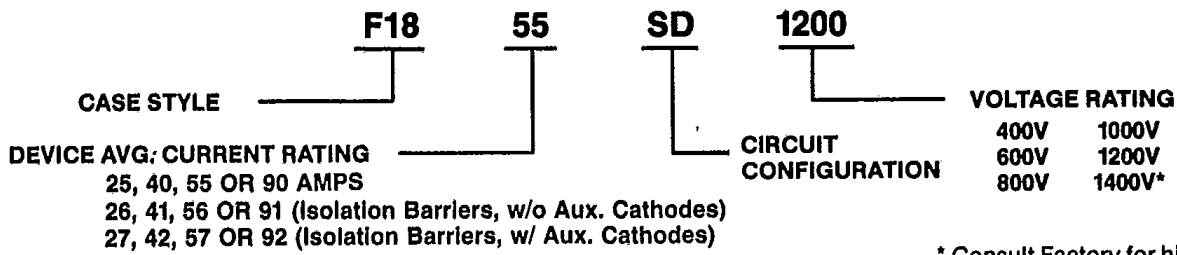


| PARAMETER | SYM. | UNITS | SPECIFICATION LIMITS | | | | CONDITIONS |
|--|--------------------|---------------------------|----------------------|------|------|--------|--|
| | | | 25 | 40 | 55 | 90 | |
| Average Output Current per Device | I_o | A | 25 | 40 | 55 | 90 | $T_c = 85^\circ\text{C}$ |
| One-Cycle Surge Current (Peak) | I_{TSM} | A | 400 | 1000 | 1500 | 1950 | $T_c = 125^\circ\text{C}$ Non-Repetitive |
| I^2t for Fusing (Max.) | I^2t | A^2S | 670 | 4150 | 9340 | 15,800 | |
| Rate-of-Rise of On-State Current (Max.) | di/dt | $\text{A}/\mu\text{S}$ | 100 | | | | Max V_{DRM} , Peak On-State Current = $9 \times I_o$ (Avg.) |
| Rate-of-Rise of Off-State Voltage (Max.) | dv/dt | $\text{V}/\mu\text{S}$ | 200* | | | | Exponential Rise to 80% V_{DRM} , Gate Open Circuit, $T_c = 125^\circ\text{C}$ |
| Reverse Blocking Voltage (Max.) | V_{RRM} | V | 200 - 1400* | | | | $T_J = 125^\circ\text{C}$ |
| Leakage Current (Max.) | I_{RM} | mA | 20 | | | | $T_J = 125^\circ\text{C}$ at Rated Voltage |
| Isolation Voltage (Min.) | V_{ISOL} | V_{rms} | 2500 | | | | Any Terminal-to-Base |
| Junction Operating and Storage Temperature Range | T_J & T_{STG} | $^\circ\text{C}$ | - 40 to + 125 | | | | |
| Thermal Resistance (Case-to-Sink) | $R_{\theta_{C-S}}$ | $^\circ\text{C}/\text{W}$ | 0.1 | | | | With Thermal Grease |
| Thermal Resistance (Junction-to-Case) | $R_{\theta_{J-C}}$ | $^\circ\text{C}/\text{W}$ | 0.67 | 0.37 | 0.20 | 0.18 | Per Module |
| Forward Gate Current (Peak) | I_{FGM} | A | 10 | | | | $T_c = 25^\circ\text{C}$ |
| Gate Current Required to Fire all Devices (Max.) | I_{GT} | mA | 150 | | | | |
| Forward Gate Voltage (Peak) | V_{FGM} | V | 30 | | | | |
| Reverse Gate Voltage (Peak) | V_{RGM} | V | 5 | | | | |
| Gate Voltage Required to Fire all Devices (Max.) | V_{GT} | V | 3 | | | | |
| Latching Current (Max.) | I_L | mA | 500 | | | | $T_c = 25^\circ\text{C}$ |
| Holding Current (Max.) | I_H | mA | 300 | | | | |
| Gate Power (Peak) | P_{GM} | W | 50 | | | | 10 μS Pulse |
| Case Style | | | F18 | | | | See following page for circuit configurations and outline dimensions |

* Higher values are available. Consult Factory.

PART NUMBER DESIGNATION CODE

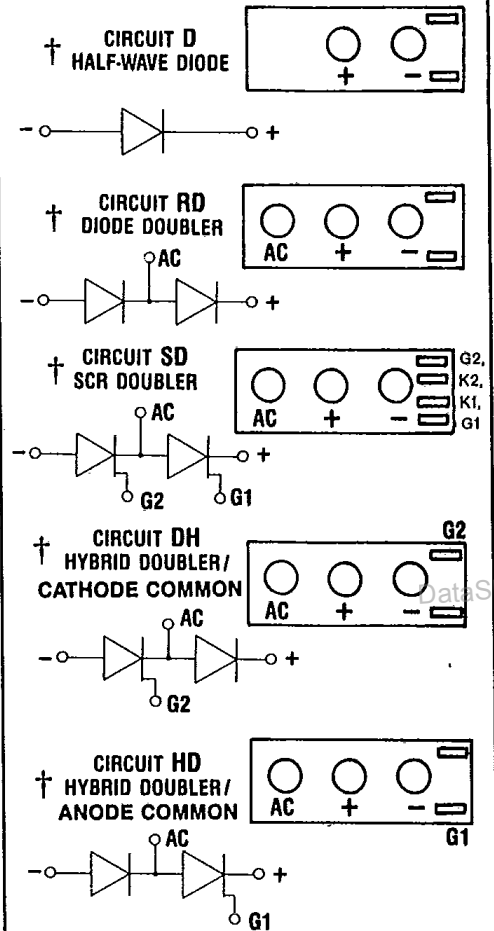
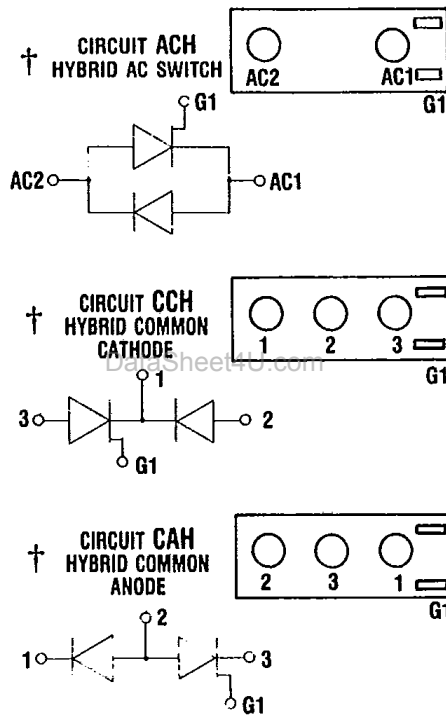
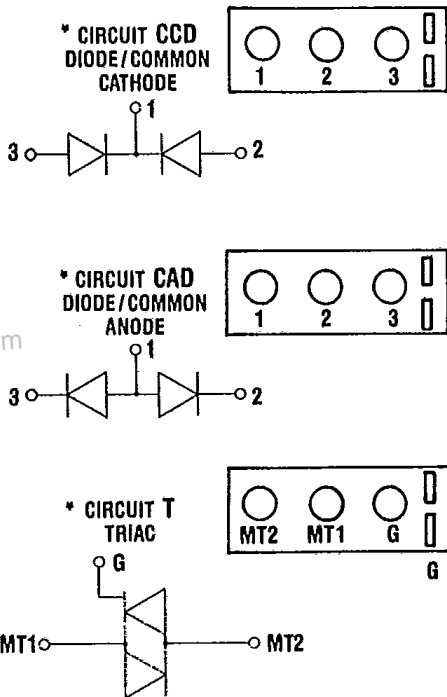
1-2-3-4-5-6-7-8-9-0



* Consult Factory for higher voltages

CIRCUIT CONFIGURATIONS

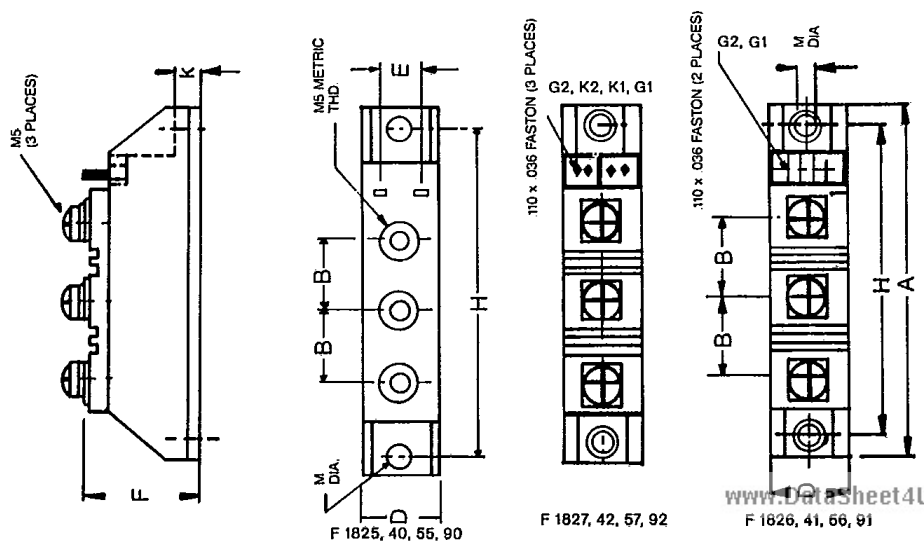
Important: Circuits marked with "*" reflect change in terminal position.
 Circuits marked with "+" reflect change in gate terminals orientation.



OUTLINE/MOUNTING DIMENSIONS

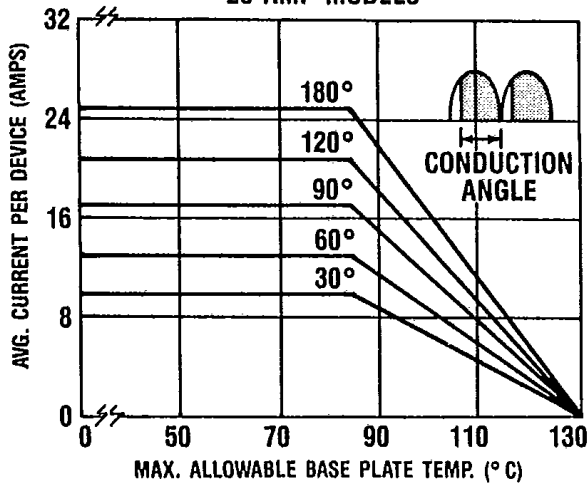
| DIM. | INCHES | | MILLIMETERS | |
|------|--------|-------|-------------|------|
| | MAX. | MIN. | MAX. | MIN. |
| A | 3.630 | 3.610 | 92.2 | 91.7 |
| B | 0.797 | 0.777 | 20.2 | 19.7 |
| D | 0.797 | 0.777 | 20.2 | 19.7 |
| E | 0.520 | 0.480 | 13.2 | 12.2 |
| F | 1.205 | 1.160 | 30.6 | 29.5 |
| G | 1.100 | 1.070 | 27.9 | 27.2 |
| H | 3.155 | 3.145 | 80.1 | 79.9 |
| J | 0.130 | 0.120 | 3.3 | 3.0 |
| K | 0.260 | 0.240 | 6.6 | 6.1 |
| L | 0.380 | 0.370 | 9.7 | 9.4 |
| M | 0.249 | 0.239 | 6.3 | 6.1 |

MOUNTING TORQUE REQUIRED:
 (A) Mounting Screws 20 in.-lbs.
 (B) Terminal Studs (Screws supplied) . 30 in.-lbs.
 Unmounted

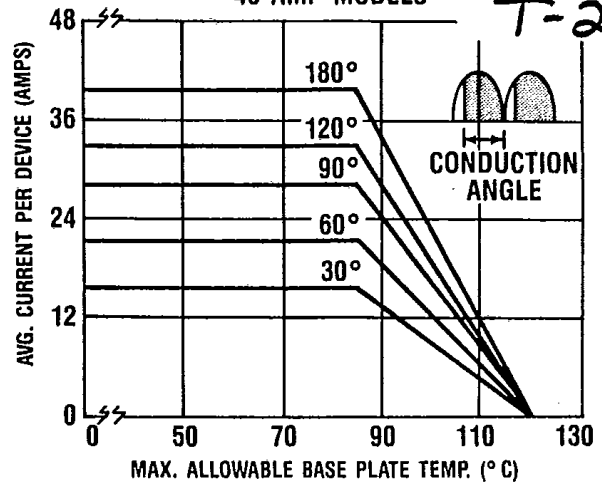


F18 SERIES MAXIMUM ALLOWABLE AVG. CURRENT PER DEVICE VS. BASE PLATE TEMPERATURE

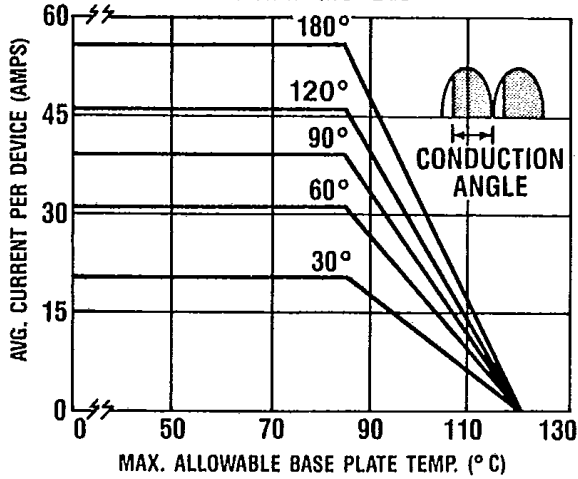
25 AMP MODELS



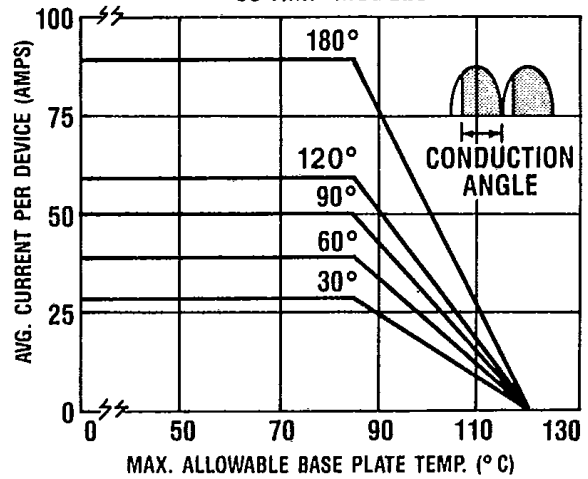
40 AMP MODELS



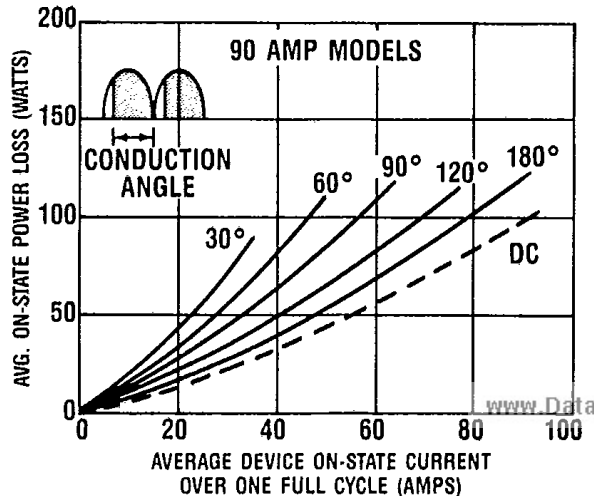
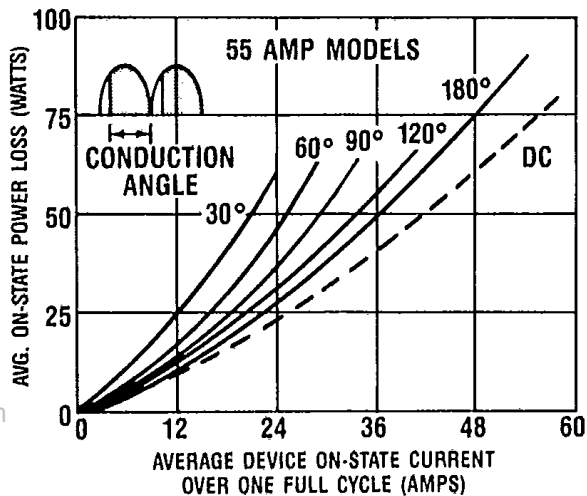
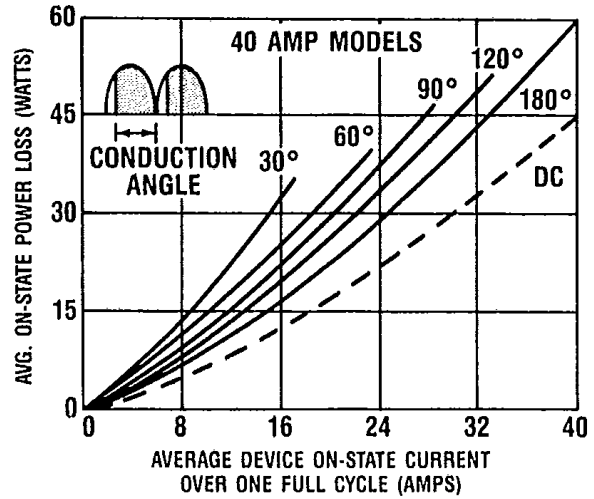
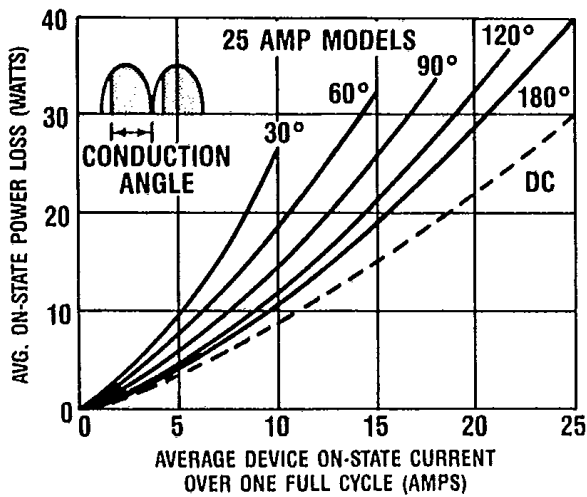
55 AMP MODELS



90 AMP MODELS

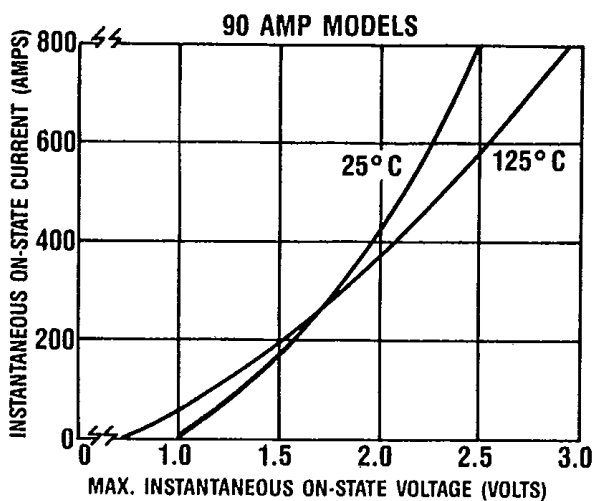
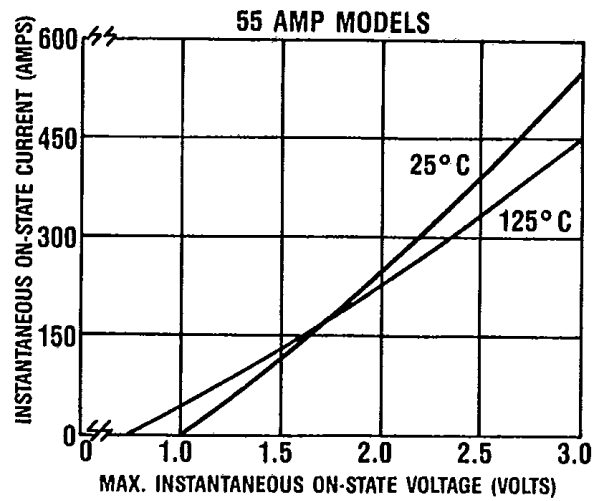
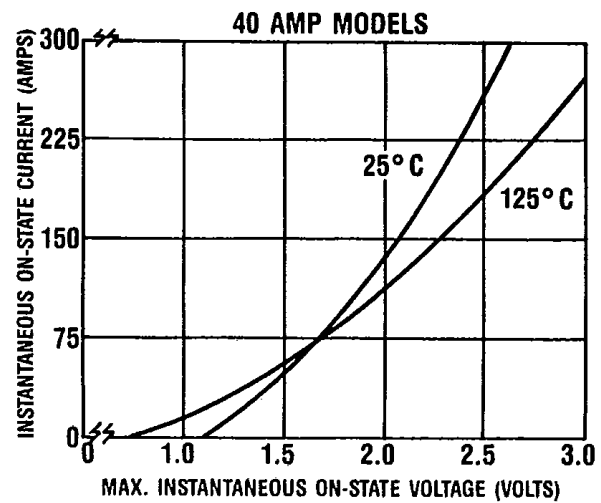
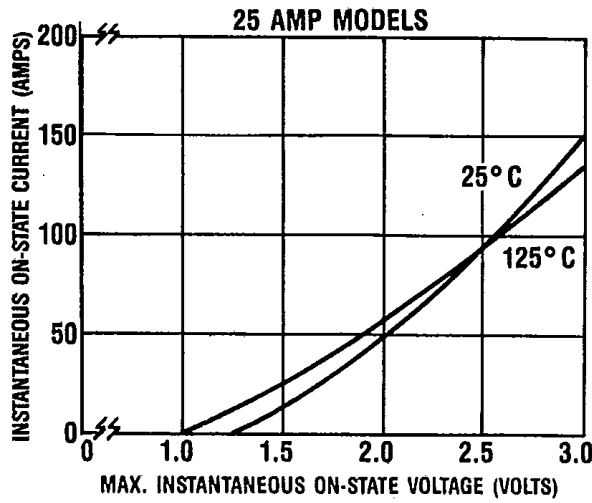


F18 SERIES AVERAGE ON-STATE POWER DISSIPATION VS. AVERAGE DEVICE CURRENT



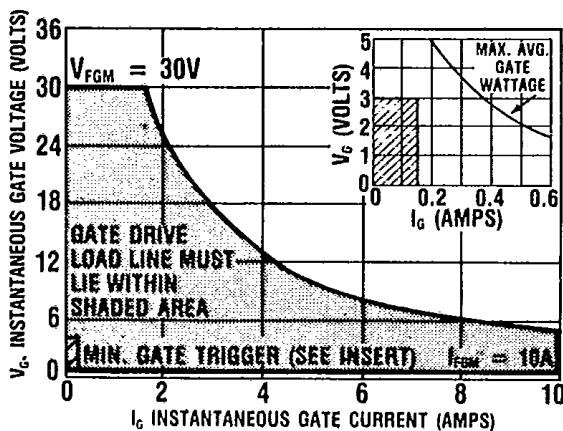
F18 SERIES MAXIMUM INSTANTANEOUS ON-STATE VOLTAGE VS. INSTANTANEOUS ON-STATE CURRENT

T-25-17



The characteristic curves shown are for each of the SCR elements (not for the total circuit). Diode element characteristic values are all equal to, or better than those shown for their companion SCR elements.

F18 SERIES GATE CHARACTERISTICS



F18 SERIES MAXIMUM NON-REPETITIVE SURGE CURRENT

